

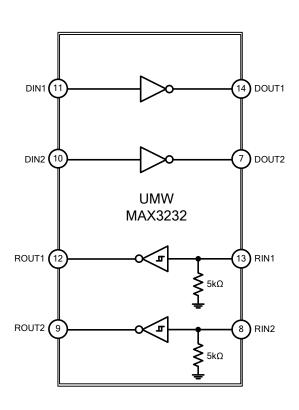
#### 1.Description

The UMW MAX3232ESE has two receivers and two drivers, and a dual charge-pump circuit. The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3.0V to 5.5V supply. The device operates at data signaling rates up to 250kbit/s and a maximum of 35V/µs driver output slew rate.

#### 2.Features

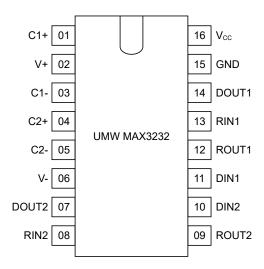
- Exceeds ±8KV ESD Protection(HBM) for RS-232 I/O Pins
- Meets the Requirements of TIA/EIA-232-F and ITU V.28 Standards
- Operates With 3.0V to 5.5V VCC Supply
- Operates Up To 250kbit/s Data Rate
- Two Drivers and Two Receivers
- External Capacitors 4×0.1µF
- Accepts 5.0V Logic Input With 3.3V Supply

#### 3.Block Diagram





### **4.Pinning Information**



**SOP-16** 

Pin No	Symbol	Function
01	C1+	Positive Terminal of Voltage-Doubler Charge-Pump Capacitor
02	V+	+5.5V Generated by the Charge Pump
03	C1-	Negative Terminal of Voltage-Doubler Charge-Pump Capacitor
04	C2+	Positive Terminal ofInverting Charge-Pump Capacitor
05	C2-	Negative Terminal of Inverting Charge-Pump Capacitor
06	V-	-5.5V Generated by the Charge Pump
07	DOUT2	RS-232 Driver Outputs
08	RIN2	RS-232 Receiver inputs
09	ROUT2	TTL/CMOS Receiver Outputs
10	DIN2	TTL/CMOS Driver inputs
11	DIN1	TTL/CMOS Driver inputs
12	ROUT1	TTL/CMOS Receiver Outputs
13	RIN1	RS-232 Receiver Inputs
14	DOUT1	RS-232 Driver Outputs
15	GND	Ground
16	V <sub>cc</sub>	+3.0V to +5.5V Supply Voltage





### **5.Absolute Maximum Ratings**

Parameter	Symbol	Ratings	Units	
Supply Voltage Range	V <sub>cc</sub>	-0.3 ~ +6.0	٧	
Positive Output Supply Voltage Range (Note 2)	V+	-0.3 ~ +7.0	V	
Negative Output Supply Voltage Range (Note 2)	V-	+0.3 ~ -7.0	V	
Supply Voltage Difference (Note 2)	V+ - V-	+13	V	
Input Voltage	Drivers	V	-0.3 ~ +6.0	V
input voltage	Receivers	V <sub>IN</sub>	-25 ~ +25	V
Output Voltage	Drivers	V	-13.2 ~ +13.2	V
Output Voltage	V <sub>OUT</sub>	-0.3 ~ V <sub>CC</sub> +0.3	V	
Operating Virtual Junction Temperature	TJ	+150	°C	
Storage Temperature		T <sub>STG</sub>	-40 ~ + 105	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### **6.Thermal Data**

Parameter	Symbol	Ratings	Units	
Junction to Ambient	SOP-16	$\theta_{JA}$	105	°C/W

<sup>2.</sup> All voltages are with respect to network GND.







### 7.Recommended Operating Conditions (See Note & Table 1)

Parameter	Symbol	Conditions		Min	Тур	Max	Units
Supply Voltage	V <sub>cc</sub>	V <sub>CC</sub> =3.3V		3	3.3	3.6	V
Supply voltage	V <sub>CC</sub>	V <sub>CC</sub> =5V		4.5	5	5.5	V
Driver and Control High-level		DIN	V <sub>CC</sub> =3.3V	2			V
Input Voltage	V <sub>IH</sub>	DIN	V <sub>CC</sub> =5.5V	2.4			V
Driver and Control Low-level Input Voltage	V <sub>IL</sub>	V <sub>IL</sub> DIN				0.8	V
Driver and Control input Voltage	V <sub>IN</sub>	DIN				5.5	V
Receiver Input Voltage	V <sub>RIN</sub>		-25		25	V	
Operating Free-Air Temperature	T <sub>A</sub>			-40		105	°C

Notes: Test conditions are C1~C4=0.1 $\mu$ F at V =3.3V±0.3V; C1=0.047 $\mu$ F, C2~C4=0.33 $\mu$ F at V<sub>CC</sub>=5.0V±0.5V.



#### **8. Electrical Characteristics**

[(over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 & Table 1)]

Parameter	Symbol	Conditions	Min	Typ (Note 1)	Max	Units
Supply Current	I <sub>cc</sub>	No load V <sub>cc</sub> =3.3V		1	3	mA
DRIVER SECTION						
High-Level Output Voltage	V <sub>OH</sub>	DOUT at $R_L$ =3k $\Omega$ to GND, DIN=GND	+5.0	+5.4		V
Low-Level Output Voltage	V <sub>OL</sub>	DOUT at $R_L$ =3k $\Omega$ to GND, DIN= $V_{CC}$	-5.0	-5.4		V
High-Level input Current	I <sub>OH</sub>	V <sub>I</sub> =V <sub>CC</sub>		±0.01	±1	μA
Low-Level input Current	I <sub>OL</sub>	V <sub>I</sub> at GND		±0.01	±1	μA
Short-Circuit Output Current		V <sub>CC</sub> =3.6V, V <sub>OUT</sub> =0V		±35	±60	mA
(Note 2)	I <sub>os</sub>	V <sub>CC</sub> =5.5V, V <sub>OUT</sub> =0V		±35	±60	mA
Output Resistance	r <sub>o</sub>	V <sub>CC</sub> , V+ and V- =0V, V <sub>OUT</sub> =±2.0V	300	10M		Ω
RECEIVER SECTION						
High-Level Output Voltage	V <sub>OH</sub>	I <sub>OH</sub> =-1.0mA	Vcc-0.6V	V <sub>cc</sub> -0.1V		V
Low-Level Output Voltage	V <sub>OL</sub>	I <sub>OH</sub> =1.6mA			0.4	V
Positive-Going linput Threshold		V <sub>CC</sub> =3.3V		1.5	2.4	V
Voltage	$V_{IT+}$	V <sub>cc</sub> =5V		1.8	2.4	V
Negative-Going Input	.,,	V <sub>CC</sub> =3.3V	0.6	1.2		V
Threshold Voltage	V <sub>IT-</sub>	V <sub>cc</sub> =5V	0.8	1.5		V
Input Hysteresis	V <sub>HYS</sub>	V <sub>IT+</sub> ~V <sub>IT-</sub>		0.3		V
Input Resistance	R <sub>i</sub>	V <sub>I</sub> =±3.0V~±25V	3	5	7	kΩ

Notes: 1. All typical values are at  $V_{CC}$ =3.3V or  $V_{CC}$ =5.0V, and  $T_A$ =25°C.

- 2. Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.
- 3. Test conditions are C1~C4=0.1 $\mu$ F at V<sub>CC</sub>=3.3V±0.3V; C1=0.047 $\mu$ F, C2~C4=0.33 $\mu$ F at V<sub>CC</sub>=5.0V±0.5V.
- 4. Pulse skew is defined as |tPLH-tPHL| of each channel of the same device.







### 9. Switching Characteristics

[over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Table 1)]

Parameter	Symbol	Conditions		Min	Typ (Note 1)	Max	Units
DRIVER SECTION							
Maximum Data Rate		C <sub>L</sub> =1000pF, R <sub>L</sub> =3	skΩ, One Driver			250	Khit/o
Maximum Data Kate		Switching				250	Kbit/s
Pulse Skew (Note 4)	t <sub>sk(p)</sub>	C <sub>L</sub> =220pF~2500ր	oF, R <sub>L</sub> =3kΩ~7kΩ		300		ns
Slow Rate Transition Region	SD/tr\	$R_L=3k\Omega\sim7k\Omega$ ,	C <sub>L</sub> =220pF~1000pF	5		35	V/µs
Slew Rate, Transition Region	SR(tr)	V <sub>CC</sub> =3.3V	C <sub>L</sub> =220pF~2500pF	3		35	V/µs
RECEIVER SECTION							
Propagation Delay Time, Low-to		C <sub>L</sub> =150pF			300		
High-Level Output	t <sub>PLH</sub>				300		ns
Propagation Delay Time, High to		C -450=5			300		200
Low-Level Output	t <sub>PHL</sub>	C <sub>L</sub> =150pF			300		ns
Output Enable Time	t <sub>EN</sub>	$C_L$ =150pF, $R_L$ =3k $\Omega$			200		ns
Output Disable Time	t <sub>DIS</sub>	$C_L$ =150pF, $R_L$ =3k $\Omega$			200		ns
Pulse Skew (Note 4)	t <sub>sk(P)</sub>	t <sub>PLH</sub> -t <sub>PHL</sub>			300		ns

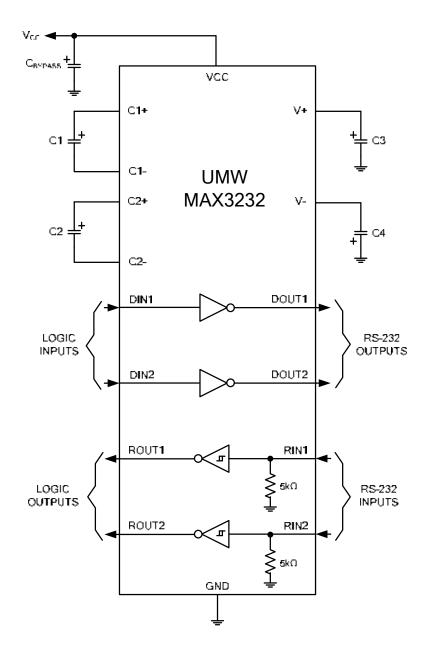
Notes: 1. All typical values are at  $V_{\text{CC}}$ =3.3V or  $V_{\text{CC}}$ =5.0V, and  $T_{\text{A}}$ =25°C.

- 2. Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.
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- 4. Pulse skew is defined as |tPLH-tPHL| of each channel of the same device.









Notes: 1.C3 can be connected to  $V_{\text{CC}}$  or GND.

- 2.Resistor yalues shown are nominal.
- 3.NC: No internal connection.
- 4. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used. they should be connected as shown.





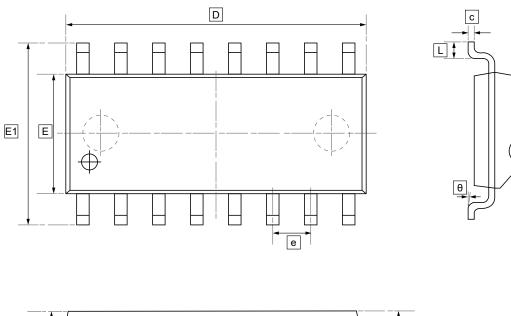


V <sub>cc</sub> (V)	C1(µF)	C2, C3, C4 (μF)
3.0~3.6	0.1	0.1
4.5~5.5	0.047	0.33
3.0~5.5	0.1	0.47

Table 1. Typical Operating Circuit and Capacitor Values



### **8.SOP-16 Package Outline Dimensions**





#### **DIMENSIONS** (mm are the original dimensions)

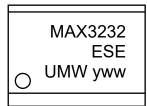
Symbol	Α	A1	A2	b	С	D	E	E1	е	L	θ
Min	1.350	0	1.350	0.330	0.170	9.800	3.800	5.800	1.270	0.400	0°
Max	1.750	0.100	1.550	0.510	0.250	10.200	4.000	6.200	BSC	1.270	8°







### 9. Ordering information



yww: Batch Code

	Order Code	der Code Package Base QTY			
ſ	UMW MAX3232ESE	SOP-16	2500	Tape and reel	







#### 10.Disclaimer

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